

SIC01XL-5

- Broadband UVA+UVB+UVC SiC photodiode,
PTB tested high chip stability
- Active Area: 4.0 mm²
- TO5 hermetically sealed metal housing
- 10μW/cm² → photocurrent of ~43nA



Description

SiC provides the unique property of extreme radiation hardness, near-perfect visible blindness, low dark current, high speed and low noise. These features make SiC the best available material for visible blind semiconductor UV detectors. The SiC detectors can be permanently operated at up to 170°C (338°F). The temperature coefficient of signal (responsivity) is also low, <-0.1%/K. Because of the low noise (dark current, in the fA range), very low UV radiation intensities can be measured reliably. Please note that this device needs an appropriate amplifier (see circuit on following page). SiC photodiodes are available as unfiltered broadband devices or with optical filters providing UV-A, UV-B, or UV-C-only sensitivity, or erythemal action curve compliance.

Maximum Ratings (T = 25°C)

| Parameter | Symbol | Values | | Unit |
|---------------------------------|------------------|--------|------|------|
| | | Min. | Max. | |
| Reverse Voltage | U _R | +20 | | V |
| Operating Temperature | T _{opr} | -55 | +170 | °C |
| Storage Temperature | T _{stg} | -55 | +170 | °C |
| Soldering Temperature (max. 3s) | T _{sol} | | +260 | °C |

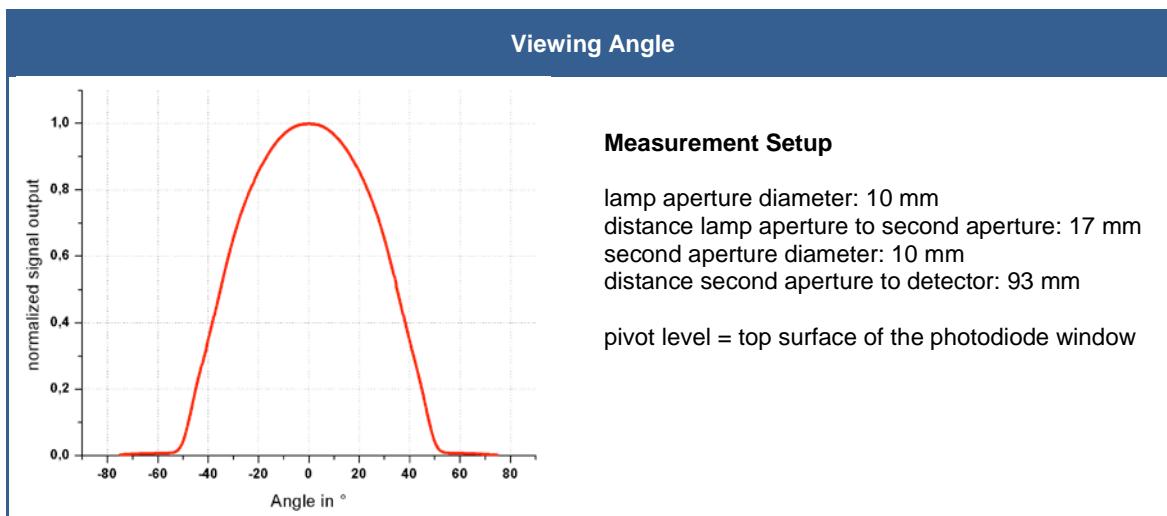
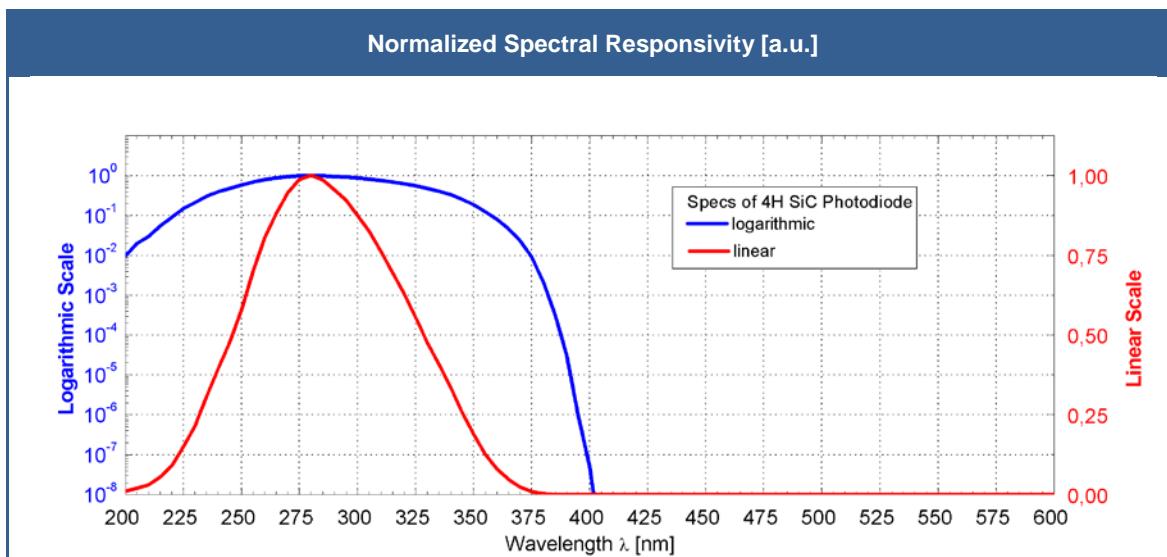
General Characteristics (T = 25°C)

| Parameter | Symbol | Min.* | Values | | Unit |
|--|----------------|-------|--------|-------|-----------------|
| | | | Typ.* | Max.* | |
| Active Area | A | | 4.0 | | mm ² |
| Dark current (1V reverse bias) | I _d | | 1.3 | | fA |
| Capacitance | C | | 1.0 | | nF |
| Short circuit (10μW/cm ² at peak) | I _b | | 43 | | nA |
| Temperature coefficient | T _c | | | -0.1 | %/K |

Spectral Characteristics (T = 25°C)

| Parameter | Symbol | Min.* | Values | | Unit |
|--|------------------|-------|------------------|-------|------------------|
| | | | Typ.* | Max.* | |
| Max. spectral responsivity | S _{max} | 0.085 | | 0.130 | AW ⁻¹ |
| Wavelength of max. spectral resp. | λ _{max} | | 280 | | nm |
| Responsivity range (S=0.1*S _{max}) | - | 220 | | 360 | nm |
| Visible blindness (S _{max} / S _{>405nm}) | VB | | 10 ¹⁰ | | - |

Performance Characteristics



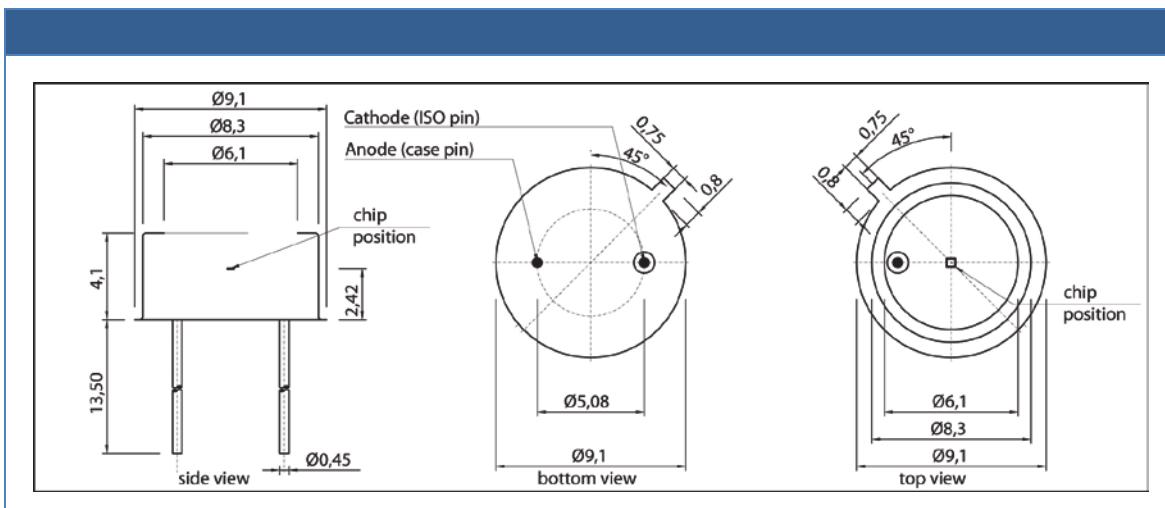
Product Portfolio

We offer the following selection of UV Photodiodes:

| Option | UV sensitivity | Detector area | Max. spectral responsivity | |
|----------------|----------------|----------------------|----------------------------|-----------------------|
| | | | min. | max. |
| SIC01S-18 | UV broadband | 0.06 mm ² | 0.085 AW ⁻¹ | 0.13 AW ⁻¹ |
| SIC01S-C18 | UVC | 0.06 mm ² | 0.066 AW ⁻¹ | 0.10 AW ⁻¹ |
| SIC01S-C5 | UVC | 0.06 mm ² | 0.066 AW ⁻¹ | 0.10 AW ⁻¹ |
| SIC01S-18ISO90 | UV broadband | 0.06 mm ² | 0.085 AW ⁻¹ | 0.13 AW ⁻¹ |
| SIC01M-18 | UV broadband | 0.2 mm ² | 0.085 AW ⁻¹ | 0.13 AW ⁻¹ |
| SIC01M-5Lens | UV broadband | 0.2 mm ² | 0.085 AW ⁻¹ | 0.13 AW ⁻¹ |
| SIC01M-C5 | UVC | 0.2 mm ² | 0.066 AW ⁻¹ | 0.10 AW ⁻¹ |
| SIC01L-18 | UV broadband | 1.0 mm ² | 0.085 AW ⁻¹ | 0.13 AW ⁻¹ |
| SIC01L-5 | UV broadband | 1.0 mm ² | 0.085 AW ⁻¹ | 0.13 AW ⁻¹ |
| SIC01L-C5 | UVC | 1.0 mm ² | 0.066 AW ⁻¹ | 0.10 AW ⁻¹ |
| SIC01XL-5 | UV broadband | 4.0 mm ² | 0.085 AW ⁻¹ | 0.13 AW ⁻¹ |

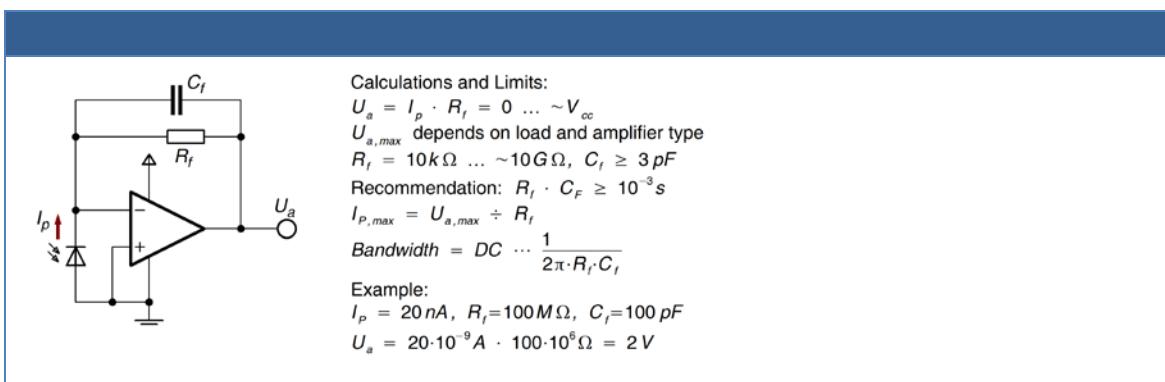
Amplified photodiodes (**TIAMO series**) are also available.

Outline Dimensions



All dimensions in mm

Circuit



Application Note

For correct reading of the photodiode the current (and NOT the voltage) must be analyzed. This requires a short circuiting of the photodiode. Usual approaches are using a Picoamperemeter or a transimpedance amplifier circuit as shown above.

To make the photodiode running reliably, particularly in harsh environment, EMC compatibility and protection against dust, water, and mechanical influences is required. Below listed modules base on a SiC photodiode and guarantee this protection and safety.

UVTIAMO: SiC photodiodes with **integrated amplifier** (0-5V output), available for power intensities ranging from 1.8 pW/cm² to 18 W/cm² for UV broadband, UVA, UVB, UVC or Erythema (UV-Index) measurements. **No additional amplifier needed, direct connection to voltmeter, controller, etc.**

UV-probe: SiC based sensor modules in **customizable industry grade housings** (e.g. cosine response, water pressure proof, sapphire windows) and **different electronic output configurations** (voltage, current, USB, Can) to choose from.

→ Ask us for further details!